

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2105	(MOS or FET or transistor) and ((first and second and third) with (diffus\$3 or impurity)) and gate and((suppress\$3 or prevent\$3 or block\$3) with diffus\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:01
L2	916	(MOS or FET or transistor) and ((first and second and third) with (diffus\$3 or impurity)) and gate and((suppress\$3 or prevent\$3 or block\$3) with diffus\$3) and (align\$3 or self-align\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:13
L3	20378	((first and second) or dual or double) with (spacer or sidewall) and gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:04
L4	236	3 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:04
L5	131	4 and (fourth with (diffus\$3 or impurity))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:05
L6	108	5 and (arsenic germanium nitrogen fluorine carbon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:06
L7	80	5 and (indium germanium nitrogen fluorine carbon)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:07
L8	80	6 and 7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:08

L9	2807	257/408,549,500.ccls. 438/163, 185,371-375.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:09
L10	8	9 and 5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:09
L11	4	((MOS or FET or transitor) and ((first and second and third) with (diffus\$3 or impurity)) and gate and((suppress\$3 or prevent\$3 or block\$3) with diffus\$3) and (align\$3 or self-align\$3)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:11
L12	194	(saiki-takashi or ohta-hiroyuki or kanata-hiroyuki).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:12
L13	3	12 and 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/21 16:13